

# Comment on "Effects of Thickness on the Spin Susceptibility of the Two Dimensional Electron Gas"

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A comment on a recent paper (PRL 94, 226405 (2005)) by S. De Palo et al.

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In a recent Letter De Palo et al. [1] claim that "Using available quantum Monte Carlo predictions for a strictly 2D electron gas, we estimate the spin susceptibility of electrons in actual devices taking into account the effect of the finite transverse thickness and finding very good agreement with experiments." In this Comment we point out that this claimed "very good agreement" is misleading and accidental because a crucial parameter (the background depletion charge density) determining the quasi-2D thickness effect in semiconductor structures is simply unknown. In Ref. 1, this parameter is uncritically assumed to be zero, whereas the theoretical results, as shown below, do depend on the depletion charge density, and even an immeasurably low depletion density (e.g.  $10^9 - 10^{10} \text{ cm}^{-2}$ ) changes the results substantially.

It is well-known that the finite thickness of the 2D electron system depends on the depletion charge density in the semiconductor heterostructure. Within the simple variational wavefunction used in Ref. 1, the width parameter  $b'$  parameterizing the quasi-2D thickness is given by  $b' = (48 m^* e^2 N_s / \epsilon^2)^{1/3}$ , where  $m^*$ ,  $\epsilon$  are the transverse carrier mass and the semiconductor dielectric constant respectively, and  $N_s = N_d + \frac{11}{32} N_s$  where  $N_d$  is the depletion charge density and  $N_s$  is the 2D carrier density. Since  $b'$  is the key quasi-2D thickness parameter modifying the effective Coulomb interaction from the strict 2D form of  $v(q) = 2 e^2 / q$  to the quasi-2D form of  $\tilde{v}(q) = v(q) F(q)$  where  $F(q) < 1$  is given by Eq. (2) of Ref. 1, an accurate knowledge of  $N_d$  is crucial in the determination of the quasi-2D thickness effect, particularly for low  $N_s$  which is the regime of experimental interest.

To emphasize the quantitative importance of the depletion charge density, we show in Fig. 1 a diagrammatic many-body calculation of the quasi-2D susceptibility using the so-called ladder-bubble (i.e. dynamically screened Hartree-Fock or RPA) approximation [2] for a series of values of  $N_d = 0 - 10^{11} \text{ cm}^{-2}$  for the same 2D GaAs HIGFET structure of Ref. 3 with which Ref. 1 carried out their QMC theoretical comparison. The most important feature of Fig. 1 is that our theory [2] also gives "very good agreement" with experimental results if we assume  $N_d = 0$  as has apparently been assumed in Ref. 1. On the other hand, any reasonable finite value of  $N_d$  leads to increasingly worse quantitative agreement with experimen-

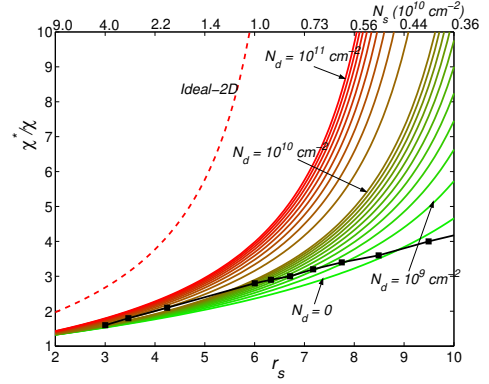


FIG. 1: (Color online.) Calculated spin susceptibility  $\chi_s$ , with  $\chi_s^0$  the renormalized (Pauli) spin susceptibility. The dashed line denotes the ideal-2D result, the marked line is the experimental GaAs data from Ref. 3, and the solid lines correspond to  $N_d$  value ranging from 0 to  $10^{10} \text{ cm}^{-2}$  (in steps of  $10^9 \text{ cm}^{-2}$ ) and then to  $10^{11} \text{ cm}^{-2}$  (in steps of  $10^{10} \text{ cm}^{-2}$ ) from bottom to top.  $r_s = (N_s)^{1/2} a_B$ , where  $a_B = \hbar^2 / (m^* e^2)$ , is the usual interaction parameter.

tal results, particularly at larger values of  $r_s$  (i.e. lower values of  $N_s$ ) where the many-body renormalization is strongest. It fact not only our theory [2], but also other theoretical approaches [4], give "very good agreement" with the experimental data of Ref. 3 if the (unknown) depletion charge density is assumed to be small (in particular  $N_d = 0$ ) as done uncritically in Ref. 1. We emphasize that the actual depletion charge density in Ref. [3] is simply not known, and hence the claim of "very good agreement" [1] between QMC results and experiment is meaningless. (Note that in our work [2] we have been very critical about this agreement, and the "good agreement" alone is not the main message of Ref. 2.)

There are other important physical mechanisms left out of consideration in Ref. 1 as well: Magneto-orbital coupling in a finite parallel field [5]; temperature [6]; spin polarization effects [2, 3, 7]; Landau quantization [8]. But based on our discussion of the depletion charge effect alone, it is already safe to conclude that the "very good agreement" between the experimental data and the QMC theory is accidental. In fact, the agreement between the QMC theory [1] and experiment is no better than in other

recent theories [2, 4] of 2D susceptibility.

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